

isc N-Channel MOSFET Transistor

RJ1G08CGN

FEATURES

- Drain Current –I_D= 80A@ T_C=25 $^\circ\!\mathrm{C}$
- Drain Source Voltage-: V_{DSS}=40V(Min)
- Static Drain-Source On-Resistance
- : $R_{DS(on)}$ = 5.6m Ω (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

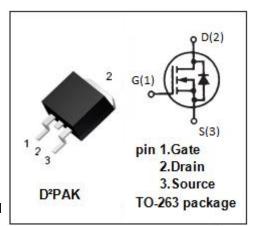
• Designed for use in switch mode power supplies and general purpose applications.

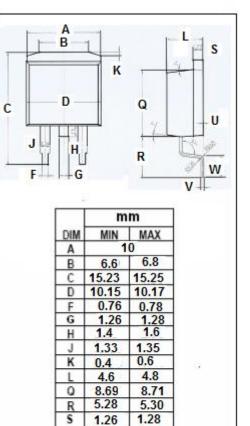
ABSOLUTE MAXIMUM RATINGS(Ta=25 C)						
SYMBOL	PARAMETER VALUE		UNIT			
V _{DSS}	Drain-Source Voltage 40		V			
V _{GS}	Gate-Source Voltage-Continuous ±20		V			
ID	Drain Current-Continuous 80		А			
I _{DM}	Drain Current-Single Pluse		А			
P _D	Total Dissipation @T _c =25°C 78		W			
TJ	Max. Operating Junction Temperature -55~150		°C			
T _{stg}	Storage Temperature -55~150		°C			

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	1.6	°C/W





0.2

0.39

2.82

U

v

0.0

W 2.80



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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V(BR)DSS	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 1mA	40		V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D = 500uA	1.0	2.5	V
$R_{\text{DS(on)}}$	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 80A		5.6	mΩ
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V;V _{DS} = 0		±500	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 40V; V _{GS} = 0		1	μA
V _{SD}	Forward On-Voltage	I _S = 65A; V _{GS} = 0		1.2	V

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